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TinyLogic HS 2-Input OR Gate

NC7S32

Description

The NC7S32 is a single 2–Input high performance CMOS OR Gate. Advanced Silicon Gate CMOS fabrication assures high speed and low power circuit operation over a broad V_{CC} range. ESD protection diodes inherently guard both inputs and output with respect to the V_{CC} and GND rails. Three stages of gain between inputs and outputs assures high noise immunity and reduced sensitivity to input edge rate.

Features

- Space Saving SOT23-5, SC-74A and SC-88A 5-Lead Packages
- Ultra Small MicroPakTM Leadless Package
- High Speed: $t_{PD} = 3.5$ ns Typ
- Low Quiescent Power: $I_{CC} < 1 \mu A$
- Balanced Output Drive: 2 mA I_{OL}, -2 mA I_{OH}
- Broad V_{CC} Operating Range: 2 V 6 V
- Balanced Propagation Delays
- Specified for 3 V Operation
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



Figure 1. Logic Symbol

	SIP6 CASE 127EB	тткк хүz
	Pin 1	*
	SC-74A CASE 318BQ	7S32M• 0 •
	SOT23–5 CASE 527AH	
	SC-88A CASE 419A-02	S32M• 0
KK XY Z M	= Specific Device (= 2-Digit Lot Run [¬] = 2-Digit Date Coc = Assembly Plant (= Date Code*	Fraceability Code le Format Code
*Date Code	orientation and/or	position may

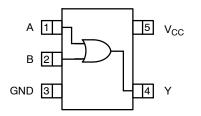
*Date Code orientation and/or position may vary depending upon manufacturing location.

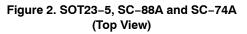
ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

MARKING DIAGRAMS

Pin Configurations





PIN DESCRIPTIONS

Pin Name	Description
A, B	Inputs
Y	Output
NC	No Connect

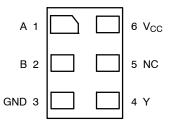


Figure 3. MicroPak (Top Through View)

FUNCTION TABLE (Y = A + B)

Inp	Output	
А	В	Y
L	L	L
L	н	Н
Н	L	Н
Н	Н	Н

H = HIGH Logic Level L = LOW Logic Level

Symbol	Paramete	r	Min	Мах	Unit
V _{CC}	Supply Voltage		-0.5	6.5	V
Ι _{ΙΚ}	DC Input Diode Current	V _{IN} < 0 V	-	-20	mA
		$V_{IN} > V_{CC}$	-	+20	
V _{IN}	DC Input Voltage		-0.5	V _{CC} + 0.5	V
I _{OK}	DC Output Diode Current V _{OUT} < 0 V		-	-20	mA
		V _{OUT} > V _{CC}	-	+20	
V _{OUT}	DC Output Voltage		-0.5	V _{CC} + 0.5	V
I _{OUT}	DC Output Source or Sink Current		-	±12.5	mA
I_{CC} or I_{GND}	DC V _{CC} or Ground Current per Output Pin		-	±25	mA
T _{STG}	Storage Temperature		-65	+150	°C
TJ	Junction Temperature		-	+150	°C
ΤL	Lead Temperature (Soldering, 10 Seconds)		-	+260	°C
PD	Power Dissipation in Still Air	SC-74A / SOT23-5	-	390	mW
		SC-88A	-	332	1
		MicroPak-6	-	812	1

ABSOLUTE MAXIMUM RATINGS

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Conditions	Min	Мах	Unit
V _{CC}	Supply Voltage		2.0	6.0	V
V _{IN}	Input Voltage		0	V _{CC}	V
V _{OUT}	Output Voltage		0	V _{CC}	V
T _A	Operating Temperature		-40	+85	°C
t _r , t _f	t _r , t _f Input Rise and Fall Times	V _{CC} at 2.0 V	0	20	ns/V
		V _{CC} at 3.0 V	0	20	
		V _{CC} at 4.5 V	0	10	
		V _{CC} at 6.0 V	0	5	
θ_{JA}	Thermal Resistance	SC-74A / SOT23-5	-	320	°C/W
		SC-88A	-	377	
		MicroPak-6	-	154	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability. 1. Unused inputs must be held HIGH or LOW. They may not float.

DC ELECTICAL CHARACTERISTICS

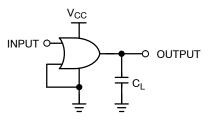
				-	Γ _A = +25°C	;	T _A = -40	to +85°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Min	Тур	Max	Min	Max	Unit
V _{IH}	HIGH Level Input Voltage	2.0 3.0 – 6.0		1.50 0.7 V _{CC}	-		1.50 0.7 V _{CC}	-	V
V _{IL}	LOW Level Input Voltage	2.0 3.0 – 6.0				0.50 0.3 V _{CC}		0.50 0.3 V _{CC}	V
V _{OH}	HIGH Level Output Voltage	2.0 3.0 4.5 6.0		1.90 2.90 4.40 5.90	2.0 3.0 4.5 6.0	- - - -	1.90 2.90 4.40 5.90	- - - -	V
		3.0 4.5 6.0	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -1.3 \text{ mA}$ $I_{OH} = -2.0 \text{ mA}$ $I_{OH} = -2.6 \text{ mA}$	2.68 4.18 5.68	2.85 4.35 5.85		2.63 4.13 5.63		V
V _{OL}	LOW Level Output Voltage	2.0 3.0 4.5 6.0	$ I_{OL} = 20 \ \mu A \\ V_{IN} = V_{IH} \ or \ V_{IL} $	- - - -	0.0 0.0 0.0 0.0	0.10 0.10 0.10 0.10 0.10	- - - -	0.10 0.10 0.10 0.10	V
		3.0 4.5 6.0	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 1.3 \text{ mA}$ $I_{OL} = 2.0 \text{ mA}$ $I_{OL} = 2.6 \text{ mA}$	- - -	0.1 0.1 0.1	0.26 0.26 0.26	- - -	0.33 0.33 0.33	V
I _{IN}	Input Leakage Current	6.0	$V_{IN} = V_{CC}, \text{ GND}$	-	-	±0.1	-	±1.0	μA
I _{CC}	Quiescent Supply Current	6.0	$V_{IN} = V_{CC}, \text{ GND}$	-	-	1.0	-	10.0	μA

AC ELECTRICAL CHARACTERISTICS

					Γ _A = +25°C)	T _A = -40	to +85°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Min	Тур	Max	Min	Max	Unit
t _{PLH} ,	Propagation Delay (Figure 4, 6)	5.0	C _L = 15 pF	-	3.5	15	-	-	ns
^t PHL		2.0 3.0 4.5 6.0	C _L = 50 pF	- - -	20 12 8 7	100 27 20 17	- - -	125 35 25 21	ns
t _{TLH} ,	Output Transition Time	5.0	C _L = 15 pF	-	3.0	10	-	-	ns
t _{THL}	(Figure 4, 6)	2.0 3.0 4.5 6.0	C _L = 50 pF	- - -	25 16 11 9	125 35 25 21	- - - -	155 45 30 26	ns
C _{IN}	Input Capacitance	Open		-	2	10	-	10	pF
C _{PD}	Power Dissipation Capacitance (Figure 5)	5.0	(Note 2)	-	6	_	_	-	pF

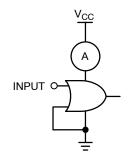
 C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle. C_{PD} is related to I_{CCD} dynamic operating current by the expression: I_{CCD} = (C_{PD}) (V_{CC}) (f_{IN}) + (I_{CC}static).

AC Loading and Waveforms



 C_L includes load and stray capacitance Input PRR = 1.0 MHz; t_W = 500 ns

Figure 4. AC Test Circuit



Input = AC Waveforms; PRR = Variable; Duty Cycle = 50%.

Figure 5. I_{CCD} Test Circuit

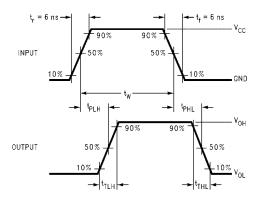


Figure 6. AC Waveforms

ORDERING INFORMATION

Part Number	Top Mark	Package Description	Shipping [†]
NC7S32M5X	7S32	SC-74A	3000 / Tape & Reel
NC7S32M5X-L22090	7S32	SOT23-5	3000 / Tape & Reel
NC7S32P5X	S32	SC-88A	3000 / Tape & Reel
NC7S32L6X	тт	SIP6, MicroPak	5000 / Tape & Reel
NC7S32L6X-L22175	тт	SIP6, MicroPak	5000 / Tape & Reel

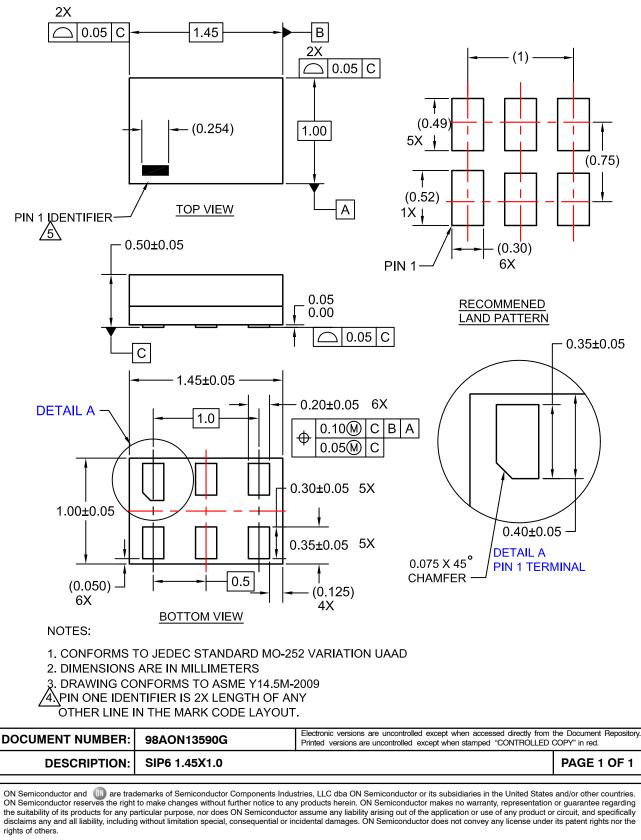
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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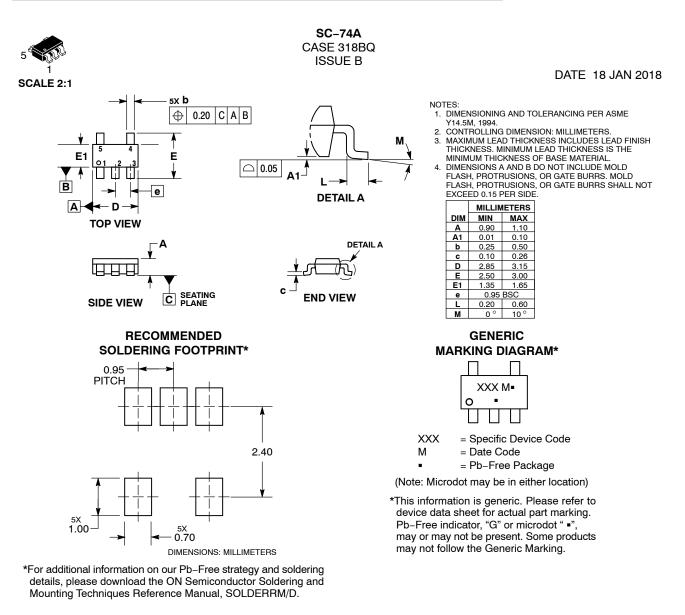


SIP6 1.45X1.0 CASE 127EB ISSUE O

DATE 31 AUG 2016







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DESCRIPTION:	SC-74A		PAGE 1 OF 1				
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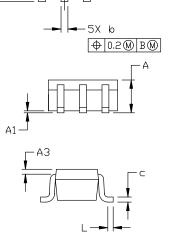


SCALE 2:1

SC-88A (SC-70-5/SOT-353) CASE 419A-02 ISSUE M

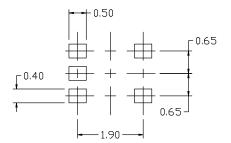
NDTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. 419A-01 DBSDLETE. NEW STANDARD 419A-02
- 4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.



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F1



RECOMMENDED MOUNTING FOOTPRINT

For additional information on our
Pb-Free strategy and soldering details,
please download the DN Semiconductor
Soldering and Mounting Techniques
Reference Manual, SDLDERRM/D.

DIM	MILLIMETERS				
ויונע	MIN.	NDM.	MAX,		
А	0.80	0.95	1.10		
A1			0.10		
A3		0.20 REF	-		
b	0.10	0.20	0.30		
C	0.10		0.25		
D	1.80	2.00	2,20		
E	2.00	2.10	5.20		
E1	1.15	1.25	1.35		
e	0.65 BSC				
L	0.10	0.15	0.30		

GENERIC MARKING





*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

PIN 1. BASE PIN 1. ANODE PIN 1. ANODE 1 PIN 1. SOURCE 1 PIN 1. CATHODE 2. EMITTER 2. EMITTER 2. N/C 2. DRAIN 1/2 2. COMMON ANODE 3. BASE 3. BASE 3. ANODE 2 3. SOURCE 1 3. CATHODE 2 4. COLLECTOR 4. COLLECTOR 4. CATHODE 2 4. GATE 1 4. CATHODE 3 5. COLLECTOR 5. CATHODE 5. CATHODE 1 5. GATE 2 5. CATHODE 4 STYLE 6: STYLE 7: STYLE 8: STYLE 9: Note: Please refer to datasheet for style callout. If style type is not callout. If style type is not callout. If style type is not callout. Collector 3. EMITTER 1 3. BASE 3. N/C 3. ANODE 2 4. ANODE 4. COLLECTOR 2/BASE 1 5. COLLECTOR 4. COLLECTOR 4. BASE 4. ANODE out in the datasheet refer to the callout. If style type is not callout. If style type is not callout. Collector 4. COLLECTOR 2/BASE 1 5. COLLECTOR 4. BASE 4. ANODE out in the datasheet refer to the callout. If out or pin assignment DOCUMENT NUMBER: 98ASB42984B Electronic versions are uncontrolled except when accessed directly from the Document F	DESCRIPTION:	SC-88A (SC-70-	5/SOT-353)			PAGE 1 OF 1
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XXX = Specific Device Code

M = Date Code = Pb-Free Package

⁽Note: Microdot may be in either location)

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